TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET

TLP3540

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Memory Testers
Logic IC Testers
Data Recording Equipment
Measuring Equipment

TLP3540 is a photorelay and consists of a GaAs infrared emitting diode optically coupled to a photo–MOSFET in a 8–pin DIP package (DIP8). This photorelay has characteristics of low–on resistance when it turns on. It is suitable for 48 V power line on / off switches.

• 1-form-A

• Peak off-state voltage: 60V(min.)

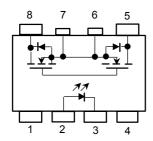
• Trigger LED current: 5mA(max.)

• On-state current: 2A(max.)

• On– state resistance: 120mΩ(max.)

• Isolation voltage: 1500V_{rms}(min.)

Pin Configuration (top view)



1 : NC

2 : Anode

3: Cathode

4 : NC

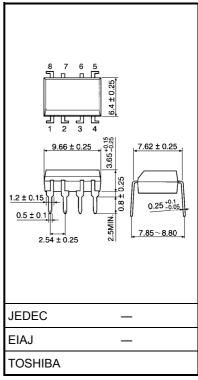
5 : Drain

6 : Source (shorten a pin)

7 : Source (shorten a pin)

8 : Drain

Unit in mm



Weight: 0.54 g

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	I _F	50	mA
LED	Reverse voltage	V _R	6	V
	Junction temperature	Tj	125	°C
J.	Off-state output voltage	V _{OFF}	60	V
Detector	On-state current	I _{ON}	2	Α
	Junction temperature	Tj	125	°C
Storage temperature		T _{stg}	-55~125	°C
Operating temperature		T _{opr}	-20~85	°C
Lead solder temperature (10 s)		T _{sol}	260	°C
Isola	ation voltage (AC, 1 min., R.H.≤ 60%) (Note 1)	BVS	1500	V _{rms}

(Note 1): Device considered a two–terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5 and 8 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{OFF}	_	_	48	V
Forward current	lF	10	_	30	mA
On-state current	I _{ON}	_	_	2	Α
Operating temperature	T _{opr}	25	_	50	°C

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 20 mA	1.0	1.2	1.4	V
LED	Reverse voltage	I _R	V _R = 6 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	15	_	pF
Detector	Off-state current	l _{OFF}	V _{OFF} = 20V, Ta = 50°C	_	1.0	4.0	nA
	Capacitance	C _{OFF}	V = 0, f = 1MHz	_	600	1400	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIn.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	I _{ON} = 1 A	_	_	5	mA
On–state resistance	R _{ON}	I _{ON} = 1 A, I _F = 10mA	_	_	0.12	Ω

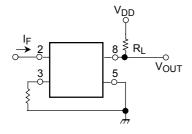
Isolation Characteristics (Ta = 25°C)

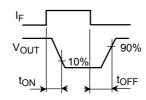
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V _S = 0V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴		Ω
		AC, 1 minute	1500	_	_	V _{rms}
Isolation voltage	BV_S	AC, 1 second (in oil)	_	3000	_	v rms
		DC, 1 minute (in oil)	_	3000	_	Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t _{ON}	$R_L = 200\Omega$ (Note2)	_	_	5	ms
Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 15 \text{ mA}$	_	_	3	1113

(Note 2): Switching time test circuit





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